CMOS Digital Integrated Circuits Silicon Monolithic

74HC00D

1. Functional Description

Quad 2-Input NAND Gate

2. General

The 74HC00D is a high speed CMOS 2-INPUT NAND GATE fabricated with silicon gate C²MOS technology. It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

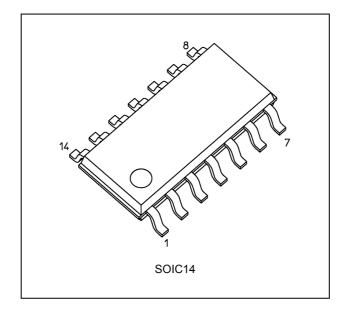
The internal circuit is composed of 3 stages including buffer output, which provide high noise immunity and stable output.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

3. Features

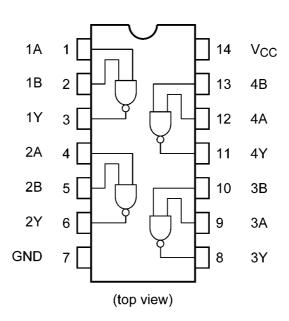
- (1) High speed: t_{pd} = 6 ns (typ.) at V_{CC} = 5 V
- (2) Low power dissipation: $I_{CC} = 1.0 \ \mu A \ (max) T_a = 25 \ ^{\circ}C$
- (3) Balanced propagation delays: $t_{PLH} \approx t_{PHL}$
- (4) Wide operating voltage range: $V_{CC(opr)} = 2.0$ to 6.0 V

4. Packaging

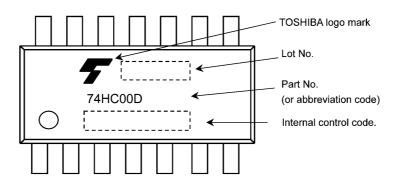


5. Pin Assignment

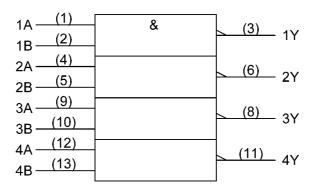
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6. Marking



7. IEC Logic Symbol



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8. Truth Table

| А | В | Y |
|---|---|---|
| L | L | Н |
| L | Н | Н |
| Н | L | Н |
| Н | Н | L |

9. Absolute Maximum Ratings (Note)

| Characteristics | Symbol | Note | Rating | Unit |
|---------------------------------|------------------|----------|-------------------------------|------|
| Supply voltage | V _{CC} | | -0.5 to 7.0 | V |
| Input voltage | V _{IN} | | -0.5 to V _{CC} + 0.5 | V |
| Output voltage | V _{OUT} | | -0.5 to V _{CC} + 0.5 | V |
| Input diode current | I _{IK} | | ±20 | mA |
| Output diode current | I _{ОК} | | ±20 | mA |
| Output current | I _{OUT} | | ±25 | mA |
| V _{CC} /ground current | I _{CC} | | ±50 | mA |
| Power dissipation | PD | (Note 1) | 500 | mW |
| Storage temperature | T _{stg} | | -65 to 150 | °C |

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: P_D derates linearly with -8 mW/°C above 85 °C

10. Operating Ranges (Note)

| Characteristics | Symbol | Test Condition | Rating | Unit |
|---------------------------|--------------------------------|----------------|----------------------|------|
| Supply voltage | V _{CC} | — | 2.0 to 6.0 | V |
| Input voltage | V _{IN} | — | 0 to V _{CC} | V |
| Output voltage | V _{OUT} | — | 0 to V _{CC} | V |
| Operating temperature | T _{opr} | _ | -40 to 125 | °C |
| Input rise and fall times | t _r ,t _f | — | 0 to 50 | μS |

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either V_{CC} or GND.

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11. Electrical Characteristics

11.1. DC Characteristics (Unless otherwise specified, $T_a = 25$ °C)

| Characteristics | Symbol | Test Conditior | ı | V _{CC} (V) | Min | Тур. | Max | Unit |
|---------------------------|-----------------|------------------------------------------|---------------------------|---------------------|------|------|------|------|
| High-level input voltage | V _{IH} | — | | 2.0 | 1.50 | _ | _ | V |
| | | | | 4.5 | 3.15 | _ | _ | |
| | | | | 6.0 | 4.20 | _ | _ | |
| Low-level input voltage | VIL | _ | | 2.0 | _ | _ | 0.50 | V |
| | | | | 4.5 | _ | _ | 1.35 | |
| | | | | 6.0 | _ | — | 1.80 | |
| High-level output voltage | V _{OH} | $V_{IN} = V_{IH} \text{ or } V_{IL}$ | I _{OH} = -20 μA | 2.0 | 1.9 | 2.0 | _ | V |
| | | | | 4.5 | 4.4 | 4.5 | _ | |
| | | | | 6.0 | 5.9 | 6.0 | _ | |
| | | | I _{OH} = -4 mA | 4.5 | 4.18 | 4.31 | _ | |
| | | | I _{OH} = -5.2 mA | 6.0 | 5.68 | 5.80 | _ | |
| Low-level output voltage | V _{OL} | $V_{IN} = V_{IH} \text{ or } V_{IL}$ | I _{OL} = 20 μA | 2.0 | | 0.0 | 0.1 | V |
| | | | | 4.5 | | 0.0 | 0.1 | |
| | | | | 6.0 | | 0.0 | 0.1 | |
| | | | I _{OL} = 4 mA | 4.5 | _ | 0.17 | 0.26 | |
| | | | I _{OL} = 5.2 mA | 6.0 | _ | 0.18 | 0.26 | |
| Input leakage current | I _{IN} | V _{IN} = V _{CC} or GND | | 6.0 | _ | _ | ±0.1 | μA |
| Quiescent supply current | I _{CC} | $V_{IN} = V_{CC}$ or GND | | 6.0 | _ | _ | 1.0 | μA |

11.2. DC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C)

| Characteristics | Symbol | Test Conditior | ı | V _{CC} (V) | Min | Max | Unit |
|---------------------------|-----------------|--------------------------------------|---------------------------|---------------------|------|------|------|
| High-level input voltage | V _{IH} | _ | | 2.0 | 1.50 | _ | V |
| | | | | 4.5 | 3.15 | _ | 1 |
| | | | | 6.0 | 4.20 | _ |] |
| Low-level input voltage | V _{IL} | — | _ | | _ | 0.50 | V |
| | | | | 4.5 | _ | 1.35 |] |
| | | | | 6.0 | _ | 1.80 |] |
| High-level output voltage | V _{OH} | $V_{IN} = V_{IH} \text{ or } V_{IL}$ | I _{OH} = -20 μA | 2.0 | 1.9 | _ | V |
| | | | | 4.5 | 4.4 | _ | |
| | | | | 6.0 | 5.9 | | |
| | | | I _{OH} = -4 mA | 4.5 | 4.13 | | |
| | | | I _{OH} = -5.2 mA | 6.0 | 5.63 | _ | |
| Low-level output voltage | V _{OL} | $V_{IN} = V_{IH} \text{ or } V_{IL}$ | I _{OL} = 20 μA | 2.0 | _ | 0.1 | V |
| | | | | 4.5 | _ | 0.1 | |
| | | | | 6.0 | — | 0.1 | |
| | | | I _{OL} = 4 mA | 4.5 | _ | 0.33 | |
| | | | I _{OL} = 5.2 mA | 6.0 | _ | 0.33 | |
| Input leakage current | I _{IN} | $V_{IN} = V_{CC}$ or GND | | 6.0 | _ | ±1.0 | μA |
| Quiescent supply current | I _{CC} | $V_{IN} = V_{CC}$ or GND | | 6.0 | _ | 10.0 | μA |

11.3. DC Characteristics (Unless otherwise specified, $T_a = -40$ to 125 °C)

| Characteristics | Symbol | Test Conditior | 1 | V _{CC} (V) | Min | Max | Unit |
|---------------------------|-----------------|------------------------------------------|---------------------------|---------------------|------|------|------|
| High-level input voltage | V _{IH} | — | | 2.0 | 1.50 | — | V |
| | | | | 4.5 | 3.15 | _ | 1 |
| | | | | 6.0 | 4.20 | _ | 1 |
| Low-level input voltage | VIL | _ | | 2.0 | _ | 0.50 | V |
| | | | | 4.5 | _ | 1.35 | 1 |
| | | | | 6.0 | _ | 1.80 | 1 |
| High-level output voltage | V _{OH} | $V_{IN} = V_{IH} \text{ or } V_{IL}$ | I _{OH} = -20 μA | 2.0 | 1.9 | _ | V |
| | | | | 4.5 | 4.4 | _ | 1 |
| | | | | 6.0 | 5.9 | _ | 1 |
| | | | I _{OH} = -4 mA | 4.5 | 3.7 | _ |] |
| | | | I _{OH} = -5.2 mA | 6.0 | 5.2 | _ | 1 |
| Low-level output voltage | V _{OL} | $V_{IN} = V_{IH} \text{ or } V_{IL}$ | I _{OL} = 20 μA | 2.0 | _ | 0.1 | V |
| | | | | 4.5 | _ | 0.1 | 1 |
| | | | | 6.0 | _ | 0.1 | 1 |
| | | | I _{OL} = 4 mA | 4.5 | _ | 0.4 | 1 |
| | | | I _{OL} = 5.2 mA | 6.0 | _ | 0.4 | 1 |
| Input leakage current | I _{IN} | $V_{IN} = V_{CC}$ or GND | · | 6.0 | — | ±1.0 | μA |
| Quiescent supply current | I _{CC} | V _{IN} = V _{CC} or GND | | 6.0 | | 40.0 | μA |

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11.4. AC Characteristics (Unless otherwise specified, $C_L = 15 \text{ pF}$, $V_{CC} = 5 \text{ V}$, $T_a = 25 \text{ °C}$, Input: $t_r = t_f = 6 \text{ ns}$)

| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|------------------------|------------------------------------|----------------|-----|------|-----|------|
| Output transition time | t _{TLH} ,t _{THL} | — | — | 4 | 8 | ns |
| Propagation delay time | t _{PLH} ,t _{PHL} | _ | _ | 6 | 12 | ns |

11.5. AC Characteristics

(Unless otherwise specified, $C_L = 50 \text{ pF}$, $T_a = 25 \text{ °C}$, Input: $t_r = t_f = 6 \text{ ns}$)

| Characteristics | Symbol | Note | V _{CC} (V) | Min | Тур. | Max | Unit |
|-------------------------------|------------------------------------|----------|---------------------|-----|------|-----|------|
| Output transition time | t_{TLH}, t_{THL} | | 2.0 | _ | 25 | 75 | ns |
| | | | 4.5 | — | 7 | 15 | |
| | | | 6.0 | _ | 6 | 13 | 1 |
| Propagation delay time | t _{PLH} ,t _{PHL} | | 2.0 | — | 27 | 75 | ns |
| | | | 4.5 | _ | 9 | 15 | |
| | | | 6.0 | _ | 8 | 13 | 1 |
| Input capacitance | C _{IN} | | _ | _ | 3 | _ | pF |
| Power dissipation capacitance | C _{PD} | (Note 1) | _ | — | 7 | — | pF |

Note 1: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.

 $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/4$ (per gate)

11.6. AC Characteristics

(Unless otherwise specified, C_L = 50 pF, T_a = -40 to 85 °C, Input: t_r = t_f = 6 ns)

| Characteristics | Symbol | V _{CC} (V) | Min | Max | Unit |
|------------------------|------------------------------------|---------------------|-----|-----|------|
| Output transition time | t _{TLH} ,t _{THL} | 2.0 | _ | 95 | ns |
| | | 4.5 | _ | 19 | |
| | | 6.0 | — | 16 | |
| Propagation delay time | t _{PLH} ,t _{PHL} | 2.0 | — | 95 | ns |
| | | 4.5 | — | 19 | |
| | | 6.0 | _ | 16 | |

11.7. AC Characteristics

(Unless otherwise specified, $C_L = 50 \text{ pF}$, $T_a = -40 \text{ to } 125 \text{ °C}$, Input: $t_r = t_f = 6 \text{ ns}$)

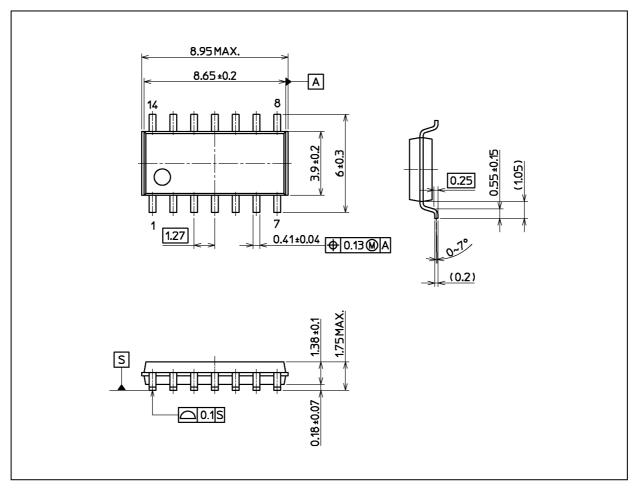
| Characteristics | Symbol | V _{CC} (V) | Min | Max | Unit |
|------------------------|------------------------------------|---------------------|-----|-----|------|
| Output transition time | t _{TLH} ,t _{THL} | 2.0 | _ | 110 | ns |
| | | 4.5 | — | 22 | |
| | | 6.0 | — | 19 | |
| Propagation delay time | t _{PLH} ,t _{PHL} | 2.0 | _ | 135 | ns |
| | | 4.5 | _ | 27 | |
| | | 6.0 | _ | 23 | |



Package Dimensions

74HC00D

Unit: mm



Weight: 0.13 g (typ.)

Package Name(s) Nickname: SOIC14

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